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## RURD420S

Data Sheet

### January 2002

## 4A, 200V Ultrafast Diodes

The RURD420S is an ultrafast diode with soft recovery characteristics ( $t_{rr}$  < 30ns). It has low forward voltage drop and has ion-implanted epitaxial planar construction.

This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. It's low stored charge and ultrafast soft recovery minimize ringing and electrical noise in many power switching circuits, reducing power loss in the switching transistors.

Formerly developmental type TA49034.

## **Ordering Information**

PART NUMBER	BER PACKAGE BRAND		
RURD420S	TO-252	RUR420	

NOTE: When ordering, use the entire part number. Add the suffix 9A to obtain the TO-252 variant in tape and reel, i.e., RURD420S9A.

## Symbol



#### Features

- Ultrafast with Soft Recovery......

- Avalanche Energy Rated
- Planar Construction

### Applications

- Switching Power Supplies
- · Power Switching Circuits
- General Purpose

## Packaging

#### JEDEC STYLE TO-252



#### Absolute Maximum Ratings T<sub>C</sub> = 25°C, Unless Otherwise Specified

	RURD420S	UNITS
Peak Repetitive Reverse VoltageV <sub>RRM</sub>	200	V
Working Peak Reverse Voltage	200	V
DC Blocking Voltage	200	V
Average Rectified Forward Current	4	A
Repetitive Peak Surge CurrentI <sub>FRM</sub> (Square Wave, 20kHz)	8	A
Nonrepetitive Peak Surge CurrentI <sub>FSM</sub> (Halfwave, 1 Phase, 60Hz)	40	A
Maximum Power Dissipation	30	W
Avalanche Energy (See Figures 9 and 10) E <sub>AVL</sub>	10	mJ
Operating and Storage Temperature	-65 to 175	°C
(Leads at 0.063 in. (1.6mm) from case for 10s)	300	°C
Package Body for 10s, see Tech Brief 334 T <sub>PKG</sub>	260	°C

#### Electrical Specifications T<sub>C</sub> = 25°C, Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	ТҮР	MAX	UNITS
V <sub>F</sub>	I <sub>F</sub> = 4A	-	-	1.0	V
	$I_{\rm F} = 4$ A, $T_{\rm C} = 150^{\rm o}$ C	-	-	0.83	V

SYMBOL	TEST CONDITION	MIN	ТҮР	MAX	UNITS
۱ <sub>R</sub>	V <sub>R</sub> = 200V	-	-	100	μΑ
	$V_{R} = 200V, T_{C} = 150^{0}C$	-	-	500	μΑ
t <sub>rr</sub>	$I_F = 1A$ , $dI_F/dt = 100A/\mu s$	-	-	30	ns
	$I_F = 4A$ , $dI_F/dt = 100A/\mu s$	-	-	35	ns
ta	$I_F = 4A$ , $dI_F/dt = 100A/\mu s$	-	11	-	ns
t <sub>b</sub>	$I_F = 4A$ , $dI_F/dt = 100A/\mu s$	-	9	-	ns
Q <sub>RR</sub>	$I_F = 4A$ , $dI_F/dt = 100A/\mu s$	-	12	-	nC
CJ	V <sub>R</sub> = 10V, I <sub>F</sub> = 0A	-	15	-	pF
$R_{ extsf{ heta}JC}$		-	-	5	°C/W

## **Electrical Specifications** $T_C = 25^{\circ}C$ , Unless Otherwise Specified

DEFINITIONS

 $V_F$  = Instantaneous forward voltage (pw = 300 µs, D = 2%).

I<sub>R</sub> = Instantaneous reverse current.

 $t_{rr}$  = Reverse recovery time (See Figure 8), summation of  $t_{a}$  +  $t_{b}$ 

 $t_a$  = Time to reach peak reverse current (See Figure 8).

t<sub>b</sub> = Time from peak I<sub>RM</sub> to projected zero crossing of I<sub>RM</sub> based on a straight line from peak I<sub>RM</sub> through 25% of I<sub>RM</sub> (See Figure 8).

 $Q_{RR}$  = Reverse recovery charge.

 $C_J$  = Junction capacitance.

 $R_{\theta JC}$  = Thermal resistance junction to case.

- pw = pulse width.
- D = duty cycle.

### **Typical Performance Curves**

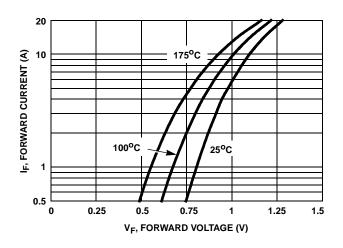


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

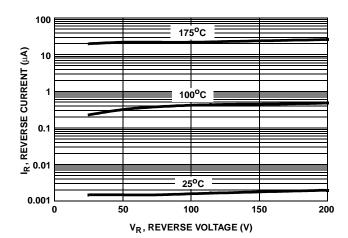


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

## Typical Performance Curves (Continued)

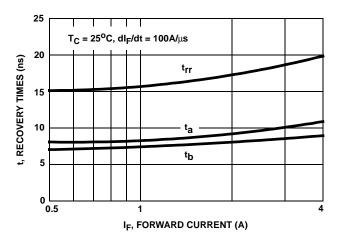


FIGURE 3. trr, ta AND tb CURVES vs FORWARD CURRENT

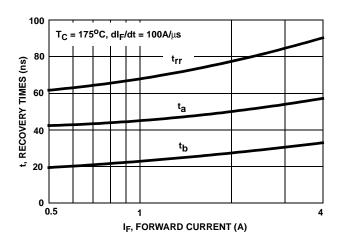


FIGURE 5.  $t_{rr}$ ,  $t_a$  AND  $t_b$  CURVES vs FORWARD CURRENT

## Test Circuits and Waveforms

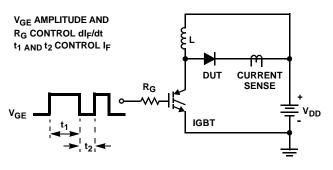


FIGURE 7. t<sub>rr</sub> TEST CIRCUIT

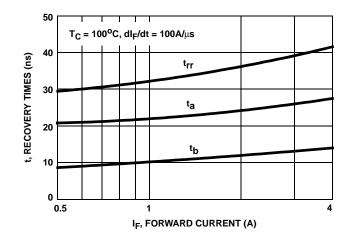


FIGURE 4. t<sub>rr</sub>, t<sub>a</sub> AND t<sub>b</sub> CURVES vs FORWARD CURRENT

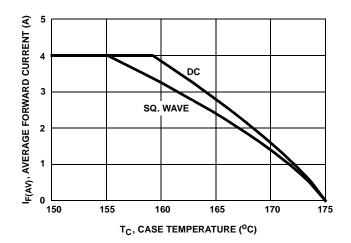


FIGURE 6. CURRENT DERATING CURVE

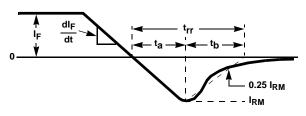


FIGURE 8. t<sub>rr</sub> WAVEFORMS AND DEFINITIONS

## Test Circuits and Waveforms (Continued)

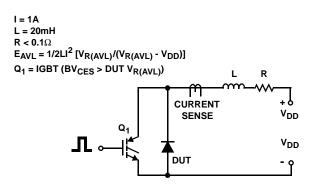


FIGURE 9. AVALANCHE ENERGY TEST CIRCUIT

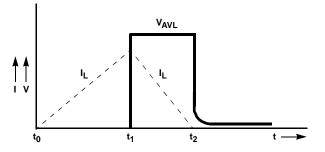


FIGURE 10. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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